## 捷多邦,专业PCB打样工厂,24小时加急出货



#### N-Channel Silicon MOSFET

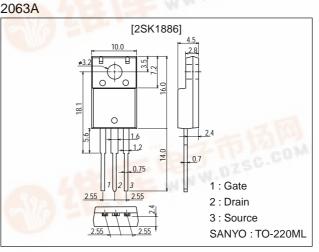
# ANYO Ultrahigh-Speed Switching Applications

## **Features**

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.
- · Micaless package facilitating mounting.

## Package Dimensions

# unit:mm



## **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		30	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±15	V
Drain Current (DC)	ID		15	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	60	A
Allowable Power Dissipation	P-	and the second	2.0	W
	PD	Tc=25°C	25	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

# Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =1mA, V <sub>GS</sub> =0	30			V
Gate-to-Source Breakdown Voltage	V(BR)GSS	I <sub>G</sub> =±100µA, V <sub>DS</sub> =0	±15		-	V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =30V, V <sub>GS</sub> =0			100	μA
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±12V, V <sub>DS</sub> =0	10-		±10	μA
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> = 1mA	1.0	107	2.0	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =9 A	7	11		S
Static Drain-to-Source ON-State Resistance	R <sub>DS(on)</sub>	I <sub>D</sub> =9A, V <sub>GS</sub> =10 <mark>V</mark>		40	55	mΩ
	R <sub>DS(on)</sub>	ID=9A, VGS=4V		55	75	mΩ

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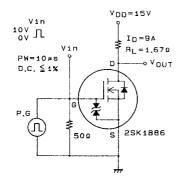
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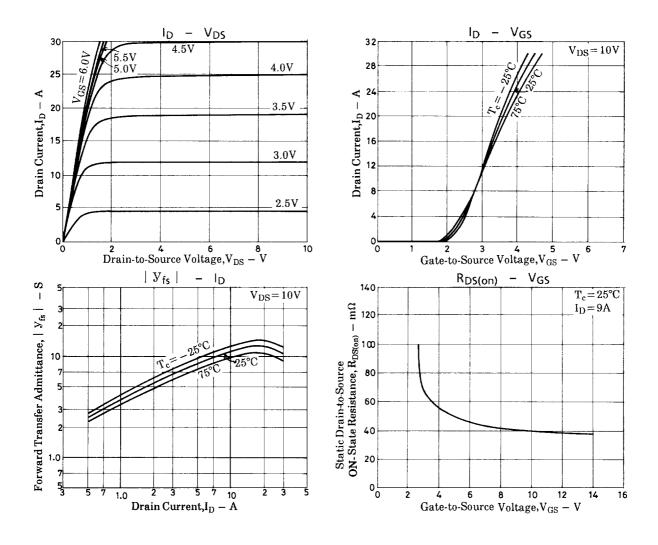
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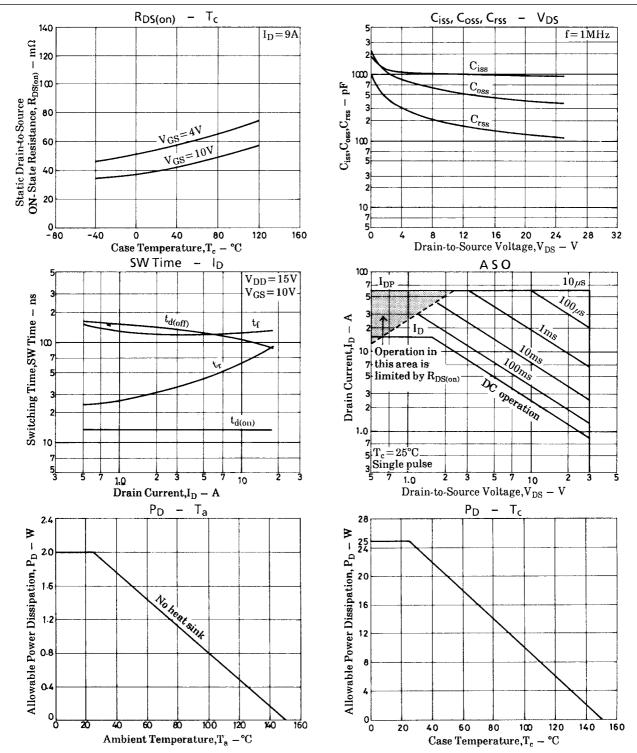
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		1000		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		550		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =10V, f=1MHz		180		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit		13		ns
Rise Time	tr	See specified Test Circuit		60		ns
Turn-OFF Delay Time	<sup>t</sup> d(off)	See specified Test Circuit		110		ns
Fall Time	tf	See specified Test Circuit		125		ns
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =15A, V <sub>GS</sub> =0		1.0	1.5	V

## **Switching Time Test Circuit**





# 2SK1886



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